

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1431

Strobe Flash Applications

Medium Power Amplifier Applications

Unit: mm

- High DC current gain and excellent h_{FE} linearity
 $: h_{FE(1)} = 100 \text{ to } 320$ ($V_{CE} = -2 \text{ V}$, $I_C = -0.5 \text{ A}$)
 $: h_{FE(2)} = 70$ (min) ($V_{CE} = -2 \text{ V}$, $I_C = -4 \text{ A}$)
- Low saturation voltage: $V_{CE(sat)} = -1.0 \text{ V}$ (max)
 $(I_C = -4 \text{ A}, I_B = -0.1 \text{ A})$

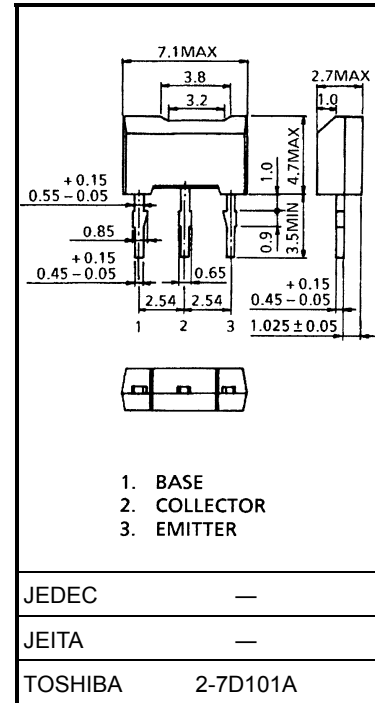
Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	-35	V
Collector-emitter voltage		V_{CEO}	-20	V
Emitter-base voltage		V_{EBO}	-8	V
Collector current	DC	I_C	-5	A
	Pulsed (Note 1)	I_{CP}	-8	
Base current		I_B	-0.5	A
Collector power dissipation		P_C	1000	mW
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

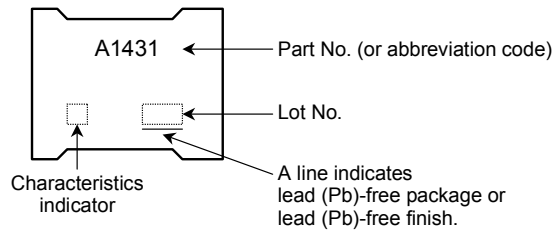
Note 1: Pulse width = 10 ms (max), duty cycle = 30% (max)

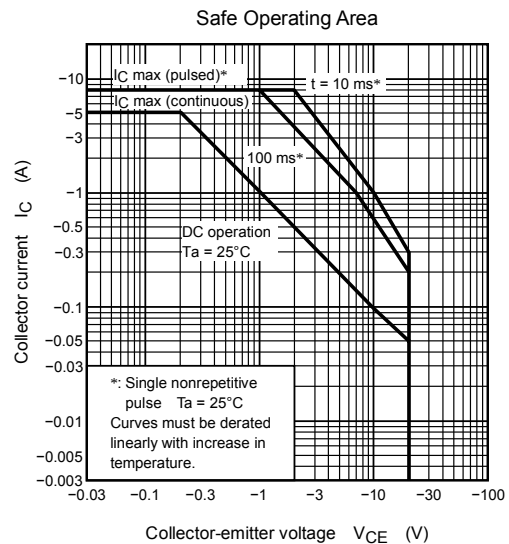
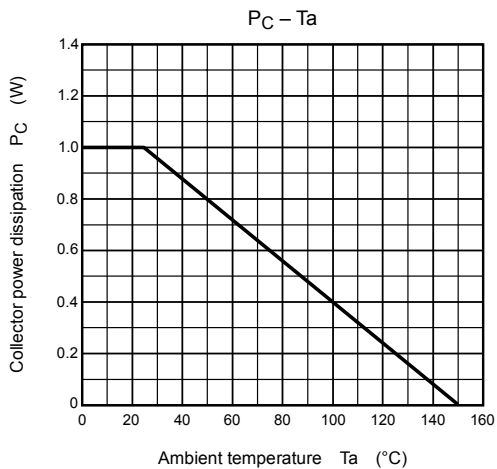
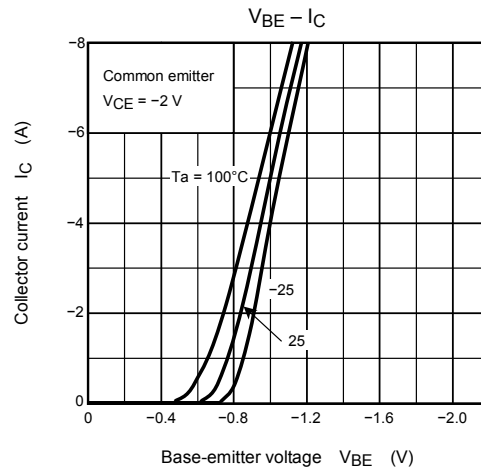
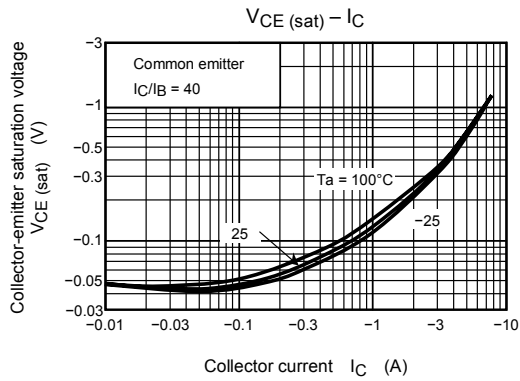
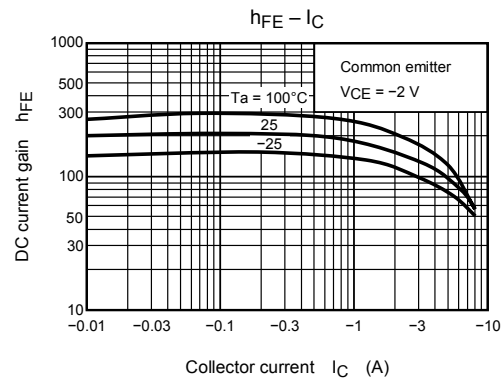
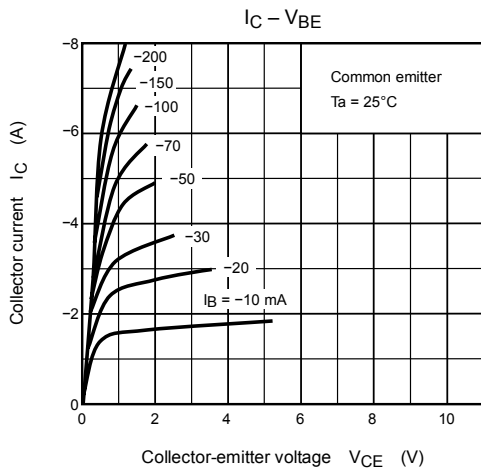
Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = -35 \text{ V}$, $I_E = 0$	—	—	-100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = -8 \text{ V}$, $I_C = 0$	—	—	-100	nA
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -10 \text{ mA}$, $I_B = 0$	-20	—	—	V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -1 \text{ mA}$, $I_C = 0$	-8	—	—	V
DC current gain	$h_{FE(1)}$ (Note 2)	$V_{CE} = -2 \text{ V}$, $I_C = -0.5 \text{ A}$	100	—	320	
	$h_{FE(2)}$	$V_{CE} = -2 \text{ V}$, $I_C = -4 \text{ A}$	70	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -4 \text{ A}$, $I_B = -0.1 \text{ A}$	—	—	-1.0	V
Base-emitter voltage	V_{BE}	$V_{CE} = -2 \text{ V}$, $I_C = -4 \text{ A}$	—	—	-1.5	V
Transition frequency	f_T	$V_{CE} = -2 \text{ V}$, $I_C = -0.5 \text{ A}$	—	170	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$	—	62	—	pF

Note 2: $h_{FE(1)}$ classification O: 100 to 200, Y: 160 to 320

Weight: 0.2 g (typ.)

Marking



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